Part II Effect of Insertion Devices on the Electron Beam

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Effect of an Insertion Device on the electron beam of a storage ring

- Perturbation of the lattice functions
 - Affect the synchrotron radiation integrals:
 - Increase energy spread, length the bunch
 - Reduce emittance
 - The effect is in general weak with the exception of the damping wigglers.

- Deflection, linear and non linear focusing from:
 - Residual field errors
 - Nominal field

Closed Orbit Distortion from Residual Field Integrals



Magnetic Field Errors



$$\theta_{x} = \frac{e}{\gamma mc} \int_{ID} B_{z}(s) ds + o(\frac{1}{\gamma})$$
$$\theta_{z} = \frac{-e}{\gamma mc} \int_{ID} B_{x}(s) ds + o(\frac{1}{\gamma})$$

$$\frac{1}{F_x} = \frac{\partial \theta_x}{\partial x} = \frac{e}{\gamma mc} \frac{\partial}{\partial x} \int_{ID} B_z(s) ds$$
$$\frac{1}{F_z} = \frac{\partial \theta_z}{\partial z} = -\frac{e}{\gamma mc} \frac{\partial}{\partial z} \int_{ID} B_x(s) ds = -\frac{1}{F_x}$$
$$\frac{1}{F_c} = \frac{\partial \theta_x}{\partial z} = \frac{e}{\gamma mc} \frac{\partial}{\partial z} \int_{ID} B_z(s) ds$$

Focusing Effect

An Insertion Device which presents a local focusing and introduces a tune shift And beta beat which are dependent on the field of the Insertion Device

$$\delta \upsilon_{x} = \frac{1}{4\pi} \int_{D} \beta_{x} K_{x} ds \simeq \frac{1}{4\pi} \frac{\beta_{x}}{F_{x}} F_{x}$$
$$\delta \upsilon_{z} = \frac{1}{4\pi} \int_{D} \beta_{z} K_{z} ds \simeq \frac{1}{4\pi} \frac{\beta_{z}}{F_{z}} F_{z}$$
$$\delta \upsilon_{c} = \frac{1}{4\pi} \frac{\sqrt{\beta_{x}} \beta_{x}}{F_{c}} F_{c}$$

and a Beta Beat :

$$\frac{\Delta\beta_x}{\beta_x} = \frac{2\pi\delta\upsilon_x}{\sin(2\pi\upsilon_x)} \quad , \quad \frac{\Delta\beta_z}{\beta_z} = \frac{2\pi\delta\upsilon_z}{\sin(2\pi\upsilon_z)}$$

- \Rightarrow Beam size variation along circumference
- \Rightarrow Stop band around half intereger resonances

=> Avoid large Beta functions in Insertion Devices

Reduction of Dynamic Aperture induced by Insertion Devices => Reduction of lifetime

- The linear focusing of an Insertion Devcie change the betatron function all over the circumference => break the N symmetry => excites non systematic resonances (normally very weak) which generate beam losses => important to locally correct the focusing and restore the beta functions
- The non linear focusing excites the non systematic resonances and may create additional losses.
- Both the nominal field and field errors can be responsible
- The effect can be serious on low energy rings with many Insertion Devices.



Point

Systematic Resonances : $mv_x+pv_z=Nq$ Non Systematic Resonances : $mv_x+pv_z=q$

m.n,q : integers

with

$$K_{x} = \frac{e}{\gamma mc} \frac{\partial B_{z}(s)}{\partial x} + K_{x}^{2nd \ order} + o(\frac{1}{\gamma^{2}})$$

$$K_{z} = -\frac{e}{\gamma mc} \frac{\partial B_{z}(s)}{\partial x} + K_{z}^{2nd \ order} + o(\frac{1}{\gamma^{2}})$$

$$K_{c} = \frac{e}{\gamma mc} \frac{\partial B_{x}(s)}{\partial x} + K_{c}^{2nd \ order} + o(\frac{1}{\gamma^{2}})$$

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Simple Theory of 2nd Order Undulator Focusing Applied to Planar Undulator

• A planar undulator presents a 2D magnetic field which in free space can be derived from a scalar potential satisfying : $\Delta \varphi(z,s) = 0$

• A solution is :
$$\varphi(z,s) = \frac{B_0 \lambda_0}{2\pi} \sinh(2\pi \frac{z}{\lambda_0}) \cos(2\pi \frac{s}{\lambda_0})$$

$$B_{z} = \frac{\partial \varphi(z,s)}{\partial z} = B_{0} \cosh(2\pi \frac{z}{\lambda_{0}}) \cos(2\pi \frac{s}{\lambda_{0}})$$
$$B_{s} = \frac{\partial \varphi(z,s)}{\partial s} = -B_{0} \sinh(2\pi \frac{z}{\lambda_{0}}) \sin(2\pi \frac{s}{\lambda_{0}})$$

• The Lorentz Force equation in such a field remains to be solved

$$\gamma m \frac{d\vec{v}}{dt} = e\vec{v} \times \vec{B}$$

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$$\frac{dv_x}{ds} = \frac{dt}{ds} \frac{e}{\gamma m} (v_z B_s - v_s B_z) \qquad B_x = 0$$

$$\frac{dv_z}{ds} = \frac{dt}{ds} \frac{e}{\gamma m} (v_s B_x - v_x B_s) \qquad \text{with} \qquad B_z = B_0 \cosh(2\pi \frac{z}{\lambda_0}) \cos(2\pi \frac{s}{\lambda_0})$$

$$\frac{dv_s}{ds} = \frac{dt}{ds} \frac{e}{\gamma m} (v_x B_z - v_z B_x) \qquad B_s = -B_0 \sinh(2\pi \frac{z}{\lambda_0}) \sin(2\pi \frac{s}{\lambda_0})$$

0 order in $1/\gamma$ •

$$\vec{v} = \begin{bmatrix} 0, 0, c \end{bmatrix}$$
$$s = ct$$

•
$$1^{st}$$
 order in $1/\gamma$

$$\vec{v} = \left[\frac{-e}{\gamma m} B_0 \frac{\lambda_0}{2\pi} \cosh(2\pi \frac{z}{\lambda_0}) \sin(2\pi \frac{s}{\lambda_0}), 0, c\right]$$

$$s = ct$$

• 2nd order in 1/
$$\gamma$$
 $\frac{dv_x}{ds} = -\frac{e}{\gamma mc} v_s B_z = \frac{-e}{\gamma m} B_0 \cosh(2\pi \frac{z}{\lambda_0}) \cos(2\pi \frac{s}{\lambda_0})$
 $\frac{dv_z}{ds} = -\frac{e}{\gamma mc} v_x B_s = -c \left(\frac{eB_0}{\gamma mc}\right)^2 \frac{\lambda_0}{2\pi} \cosh(2\pi \frac{z}{\lambda_0}) \sinh(2\pi \frac{z}{\lambda_0}) \sin^2(2\pi \frac{s}{\lambda_0})$
 $\frac{dv_s}{ds} = \frac{e}{\gamma mc} v_x B_z = -c \left(\frac{eB_0}{\gamma mc}\right)^2 \frac{\lambda_0}{2\pi} \cosh^2(2\pi \frac{z}{\lambda_0}) \cos(2\pi \frac{s}{\lambda_0}) \sin(2\pi \frac{s}{\lambda_0})$

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• averaging over one period

$$\frac{dv_x}{ds} = 0$$
$$\frac{dv_z}{ds} = -\frac{c}{2} \left(\frac{eB_0}{\gamma mc}\right)^2 \frac{\lambda_0}{4\pi} \sinh(4\pi \frac{z}{\lambda_0})$$
$$\frac{dv_s}{ds} = 0$$

• or

$$\frac{d^2 z}{ds^2} = \frac{d}{ds} \left(\frac{dz}{dt}\frac{dt}{ds}\right) = \frac{d}{ds} \left(\frac{v_z}{c}\right) \approx -\frac{1}{2} \left(\frac{eB_0}{\gamma mc}\right)^2 \left(z + \frac{16\pi^2}{6\lambda_0^2}z^3 + \dots\right) \approx -\frac{1}{2} \left(\frac{eB_0}{\gamma mc}\right)^2 z \quad \text{if} \quad z \ll \frac{\lambda_0}{4\pi}$$

Planar Undulators are vertically focusing with a focal length :

$$K_{z} = \frac{1}{2} \left(\frac{eB_{0}}{\gamma mc} \right)^{2} \quad , \qquad \qquad \frac{1}{F_{z}} = \int_{ID} K_{z} ds = \frac{1}{2} \left(\frac{eB_{0}}{\gamma mc} \right)^{2} L = \frac{e^{2}}{\gamma^{2} m^{2} c^{2}} \int B_{z}^{2} ds$$

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General Theory of 2nd Order Focusing

Start from the Lorentz Force Equation of motion of an electron in an arbitrary magnetic field expressed in a fixed Cartesian frame (Oxzs)

Solve these equations in power series of $1/\gamma$ making use of the Maxwell Equation : $\vec{\nabla}\vec{B} = 0$, $\vec{\nabla} \times \vec{B} = 0$ Insertion Device extends from s = 0 to L :

Field Errors Nominal Field

$$\frac{dx}{ds}(L) = \frac{dx}{ds}(0) + \frac{e}{\gamma mc} \int_{0}^{L} B_z ds + \frac{1}{2} (\frac{e}{\gamma mc})^2 \frac{\partial \Phi}{\partial x} + o(\frac{1}{\gamma^2})$$

$$\frac{dz}{ds}(L) = \frac{dz}{ds}(0) - \frac{e}{\gamma mc} \int_{0}^{L} B_x ds + \frac{1}{2} (\frac{e}{\gamma mc})^2 \frac{\partial \Phi}{\partial z} + o(\frac{1}{\gamma^2})$$
with $\Phi(x, z) = \int_{0}^{L} \left(\int_{0}^{s} B_x(x, z, s') ds'\right)^2 + \left(\int_{0}^{s} B_z(x, z, s') ds'\right)^2 ds$

For a periodic field with period λ_0 :

$$\Phi(x,z) = N \int_{0}^{\lambda_{0}} \left(\int_{0}^{s} B_{x}(x,z,s') ds' \right)^{2} + \left(\int_{0}^{s} B_{z}(x,z,s') ds' \right)^{2} ds$$

The detailed deflection, focusing and non-linear focusing can be predicted From the function $\Phi(x,z)$ computed from the transverse field

Tracking of e- beam in an Insertion Device

Split the Undulator into n thin Lenses separated by drift spaces



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2nd Order Focusing from High Field Wigglers

Vertical Field under Pole

PPM
100
10
2.2
2
60
6
4



Horizontal Deflection [micro-rad] vs Horizontal Position



In extreme cases (high field Wiggler, Narrow Pole, Low Energy), one may not be able to inject in a Wiggler because of the horizontal non linearity . Example : SPEAR BL11 Wiggler

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Reduction of Dynamic Aperture from Apple II

Period = 88 mm Gap = 16 mm Length = 3.2 m Betax,z = 35, 2.5 m



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Conclusion

- Insertion devices may be the source of perturbations :
 - Closed Orbit distortion
 - Tune shift
 - Lifetime reduction
- The problem is most severe on low energy rings with many insertion devices.
- Nowadays the technique of field shimming allows to get rid of most of the perturbations induced by the residual field errors.
- For high field devices or complicated field geometries (Apple II), one may need local correctors.